### INTEGRATED CIRCUITS

# DATA SHEET

# 74LV251

8-input multiplexer (3-State)

Product specification
Supersedes data of 1997 Apr 10
IC24 Data Handbook





### 8-input multiplexer (3-State)

74LV251

#### **FEATURES**

- Optimized for low voltage applications: 1.0 to 3.6 V
- ullet Accepts TTL input levels between  $V_{CC}$  = 2.7 V and  $V_{CC}$  = 3.6 V
- $\bullet$  Typical V<sub>OLP</sub> (output ground bounce) < 0.8 V at V<sub>CC</sub> = 3.3 V,  $T_{amb}$  = 25°C
- $\bullet$  Typical V<sub>OHV</sub> (output V<sub>OH</sub> undershoot) > 2 V at V<sub>CC</sub> = 3.3 V,  $T_{amb} = 25^{\circ}\text{C}$
- True and complement outputs
- Both outputs are 3-State for further multiplexer expansion
- Multifunction capability
- Permits multiplexing from n-lines to one line
- Output capability: standard
- I<sub>CC</sub> category: MSI

#### **DESCRIPTION**

The 74LV251 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT251.

The 74LV251 is an 8-input multiplexer with 8 binary inputs ( $I_0$  to  $I_7$ ), an output enable input ( $\overline{OE}$ ) and three select inputs ( $S_0$ ,  $S_1$ ,  $S_2$ ). One of the eight binary inputs is selected by the select inputs and is routed to the outputs ( $\overline{Y}$ , Y). Both outputs are in the high impedance OFF-state (Z) when the output enable input is HIGH, allowing multiplexer expansion by tying the outputs.

#### **QUICK REFERENCE DATA**

GND = 0 V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay $I_n$ to $Y$ $I_n$ to $\overline{Y}$ $S_n$ to $Y$ $S_n$ to $\overline{Y}$	C <sub>L</sub> = 15 pF; V <sub>CC</sub> = 3.3 V	14 16 19 20	ns
C <sub>I</sub>	Input capacitance		3.5	pF
C <sub>PD</sub>	Power dissipation capacitance per gate	$V_{CC} = 3.3 \text{ V}$ $V_I = \text{GND to } V_{CC}^1$	44	pF

#### NOTE:

#### **ORDERING INFORMATION**

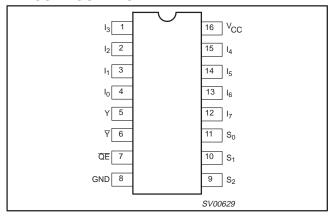
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic DIL	-40°C to +125°C	74LV251 N	74LV251 N	SOT38-4
16-Pin Plastic SO	-40°C to +125°C	74LV251 D	74LV251 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV251 DB	74LV251 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV251 PW	74LV251PW DH	SOT403-1

<sup>1.</sup>  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W)  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;  $C_L$  = output load capacitance in pF;  $f_o$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;  $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

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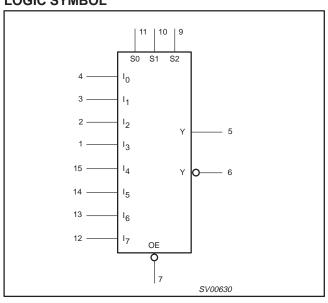
#### **PIN CONFIGURATION**



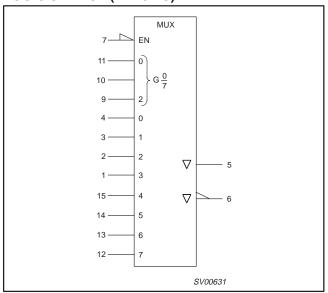
#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	FUNCTION
4, 3, 2, 1, 15, 14, 13, 12	I <sub>0</sub> to I <sub>7</sub>	Multiplexer inputs
5	Υ	Multiplexer output
6	Y	Complementary multiplexer output
7	ŌĒ	3-State output enable input (active LOW)
8	GND	Ground (0 V)
11, 10, 9	S <sub>0</sub> to S <sub>2</sub>	Select inputs
16	V <sub>CC</sub>	Positive supply voltage

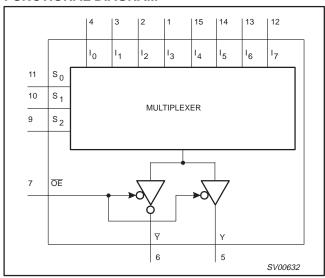
#### **LOGIC SYMBOL**



### LOGIC SYMBOL (IEEE/IEC)



#### **FUNCTIONAL DIAGRAM**



### 8-input multiplexer (3-State)

74LV251

#### **FUNCTION TABLE**

					INP	UTS						OUT	PUTS
ŌĒ	S <sub>2</sub>	S <sub>1</sub>	S <sub>0</sub>	l <sub>0</sub>	I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>	14	I <sub>5</sub>	l <sub>6</sub>	l <sub>7</sub>	Y	Υ
Н	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Z	Z
L L	L L	L L	L L	L H	X X	X X	X X	X X	X X	X X	X X	H L	L H
L L	L L	L L	H	X X	H	X X	X X	X X	X X	X X	X X	H L	L H
L	L L L	ннн	JJII	X X X	X X X	L H X X	X X L H	X X X	X X X	X X X	X X X	H L H L	L H L H
L L L	H H H	L L L	L H H	X X X	X X X	X X X	X X X	L H X X	X X L H	X X X	X X X	H L H L	L H L H
L L L	H H H	H H H	L L H	X X X	X X X	X X X	X X X	X X X	X X X	L H X	X X L	H L H	L H L
L	Н	Н	Н	Х	Х	Х	Х	Х	Х	Х	Н	L	Н

#### NOTES:

H = HIGH voltage level L = LOW voltage level

X = don't care

Z = high impedance OFF-state

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	See Note 1	1.0	3.3	3.6	V
$V_{I}$	Input voltage		0	-	V <sub>CC</sub>	V
Vo	Output voltage		0	_	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.0V \text{ to } 2.0V$ $V_{CC} = 2.0V \text{ to } 2.7V$ $V_{CC} = 2.7V \text{ to } 3.6V$	- - -	- - -	500 200 100	ns/V

#### NOTE:

<sup>1.</sup> The LV is guaranteed to function down to  $V_{CC}$  = 1.0V (input levels GND or  $V_{CC}$ ); DC characteristics are guaranteed from  $V_{CC}$  = 1.2V to  $V_{CC}$  = 5.5V.

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#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
± I <sub>IK</sub>	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5V$	20	mA
± I <sub>OK</sub>	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5 V$	50	mA
±I <sub>O</sub>	DC output source or sink current  – standard outputs	$-0.5V < V_O < V_{CC} + 0.5V$	25	mA
±I <sub>GND</sub> , ±I <sub>CC</sub>	DC V <sub>CC</sub> or GND current for types with – standard outputs		50	mA
T <sub>stg</sub>	Storage temperature range		–65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package  – plastic DIL  – plastic mini-pack (SO)  – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

#### NOTES:

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-4	0°C to +8∜	5°C	-40°C to	+125°C	UNIT
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	1
		V <sub>CC</sub> = 1.2 V	0.9			0.9		
V <sub>IH</sub>	HIGH level Input voltage	V <sub>CC</sub> = 2.0 V	1.4			1.4		٧
	l silage	V <sub>CC</sub> = 2.7 to 3.6 V	2.0			2.0		1
		V <sub>CC</sub> = 1.2 V			0.3		0.3	
$V_{IL}$	LOW level Input voltage	V <sub>CC</sub> = 2.0 V			0.6		0.6	V
	Vollago	V <sub>CC</sub> = 2.7 to 3.6 V			0.8		0.8	1
		$V_{CC} = 1.2 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 100 \mu\text{A}$		1.2				
.,	HIGH level output	$V_{CC} = 2.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 100 \mu\text{A}$	1.8	2.0		1.8		1 ,,
V <sub>OH</sub>	voltage; all outputs	$V_{CC} = 2.7 \text{ V; } V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	2.5	2.7		2.5		· V
		$V_{CC} = 3.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 100 \mu\text{A}$	2.8	3.0		2.8		1
V <sub>OH</sub>	HIGH level output voltage; STANDARD outputs	$V_{CC} = 3.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 6\text{mA}$	2.40	2.82		2.20		V
		$V_{CC} = 1.2 \text{ V; } V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0				
.,	LOW level output	$V_{CC} = 2.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu\text{A}$		0	0.2		0.2	1 .,
V <sub>OL</sub>	voltage; all outputs	$V_{CC} = 2.7 \text{ V; } V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2	٧
		$V_{CC} = 3.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu\text{A}$		0	0.2		0.2	1
V <sub>OL</sub>	LOW level output voltage; STANDARD outputs	$V_{CC} = 3.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; I_O = 6\text{mA}$		0.25	0.40		0.50	V

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 8-input multiplexer (3-State)

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### DC ELECTRICAL CHARACTERISTICS (Continued)

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-40	°C to +8	5°C	-40°C to	UNIT	
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	
I <sub>I</sub>	Input leakage current	$V_{CC} = 3.6 \text{ V}; V_I = V_{CC} \text{ or GND}$			1.0		1.0	μА
I <sub>CC</sub>	Quiescent supply current; MSI	$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$			20.0		160	μА
Δl <sub>CC</sub>	Additional quiescent supply current per input	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}; V_1 = V_{CC} - 0.6 \text{ V}$			500		850	μА

#### NOTE:

#### **AC CHARACTERISTICS**

GND = 0V;  $t_r$  =  $t_f$  = 2.5ns;  $C_L$  = 50pF;  $R_L$  = 1K $\Omega$ 

	,		CONDITION			LIMITS				
SYMBOL	PARAMETER	WAVEFORM	CONDITION	_	40 to +85 °	,C	-40 to	+125 °C	UNIT	
			V <sub>CC</sub> (V)	MIN	TYP <sup>1</sup>	MAX	MIN	MAX		
			1.2		90					
l	Propagation delay		2.0		31	58		70		
t <sub>PHL</sub> /t <sub>PLH</sub>	I <sub>n</sub> to Y	Figure 1	2.7		23	43		51	ns	
			3.0 to 3.6		17 <sup>2</sup>	34		41		
			1.2		100					
	Propagation delay	Figure 2	2.0		34	65		77		
t <sub>PHL</sub> /t <sub>PLH</sub>	$I_n$ to $\overline{Y}$	Figure 2	2.7		25	48		56	ns	
		1 [	3.0 to 3.6		19 <sup>2</sup>	38		45		
			1.2		120					
	Propagation delay S <sub>n</sub> to Y	Figure 4	2.0		41	77		92		
t <sub>PHL</sub> /t <sub>PLH</sub>		Figure 1	2.7		30	56		68	ns	
			3.0 to 3.6		23 <sup>2</sup>	45		54		
			1.2		125					
	Propagation delay S <sub>n</sub> to Ÿ	Figure 2	2.0		43	82		97	no	
t <sub>PHL</sub> /t <sub>PLH</sub>	$S_n$ to $\overline{Y}$	Figure 2	2.7		31	60		71	ns	
			3.0 to 3.6		24 <sup>2</sup>	48		57		
			1.2		65					
	3-State output disable time	Figure 2	2.0		22	43		51		
t <sub>PZH</sub> /t <sub>PZL</sub>	OE to Y, Y	Figure 2	2.7		16	31		38	ns	
			3.0 to 3.6		12 <sup>2</sup>	25		30		
			1.2		60					
l	3-State output disable time	Figure 2	2.0		22	39		48		
t <sub>PHZ</sub> /t <sub>PLZ</sub>	OE to Y, Y	Figure 2	2.7		17	29		36	ns	
		<u>                                     </u>	3.0 to 3.6		13 <sup>2</sup>	24		29		

<sup>1.</sup> All typical values are measured at  $T_{amb}$  = 25°C.

<sup>1.</sup> Unless otherwise stated, all typical values are measured at  $T_{amb}$  = 25°C 2. Typical values are measured at  $V_{CC}$  = 3.3 V.

### 8-input multiplexer (3-State)

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#### **AC WAVEFORMS**

 $V_M$  = 1.5 V at  $V_{CC} \geq$  2.7 V

 $V_{M}$  = 0.5 V ×  $V_{CC}$  at  $V_{CC}$  < 2.7 V

 $V_{\mbox{\scriptsize OL}}$  and  $V_{\mbox{\scriptsize OH}}$  are the typical output voltage drop that occur with the output load.

 $V_X = V_{OL} + 0.3 \text{ V at } V_{CC} \ge 2.7 \text{ V}$ 

 $V_X$  =  $V_{OL}$  + 0.1  $\times$   $V_{CC}$  at  $V_{CC}$  < 2.7 V

 $\begin{aligned} & V_Y = V_{OH} - 0.3 \text{ V at } V_{CC} \geq 2.7 \text{V} \\ & V_Y = V_{OH} - 0.1 \times V_{CC} \text{ at } V_{CC} < 2.7 \text{ V} \end{aligned}$ 

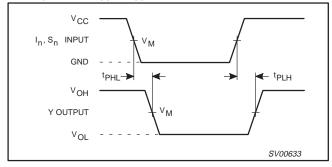


Figure 1. Multiplexer input (In) and select input (Sn) to output (Y) propagation delays.

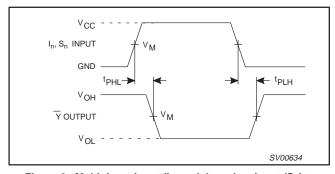


Figure 2. Multiplexer input  $(I_n)$  and the select input  $(S_n)$  to output  $(\overline{Y})$  propagation delays.

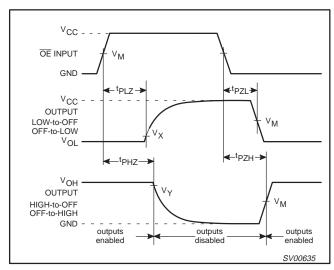


Figure 3. 3-State enable and disable times

#### **TEST CIRCUIT**

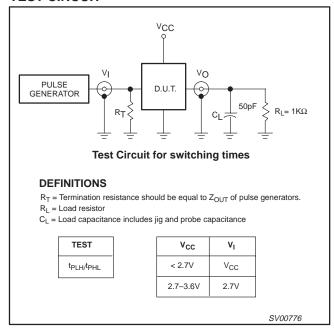


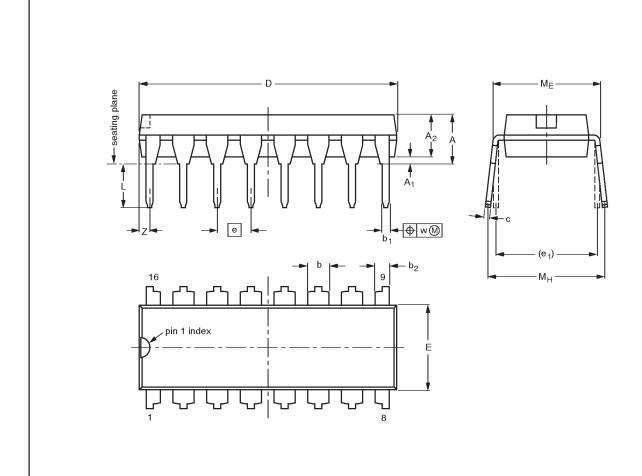
Figure 4. Load circuitry for switching times.

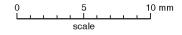
# 8-input multiplexer (3-State)

74LV251

### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4





#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTI		ISSUE DATE
SOT38-4						<del>92-11-17</del> 95-01-14

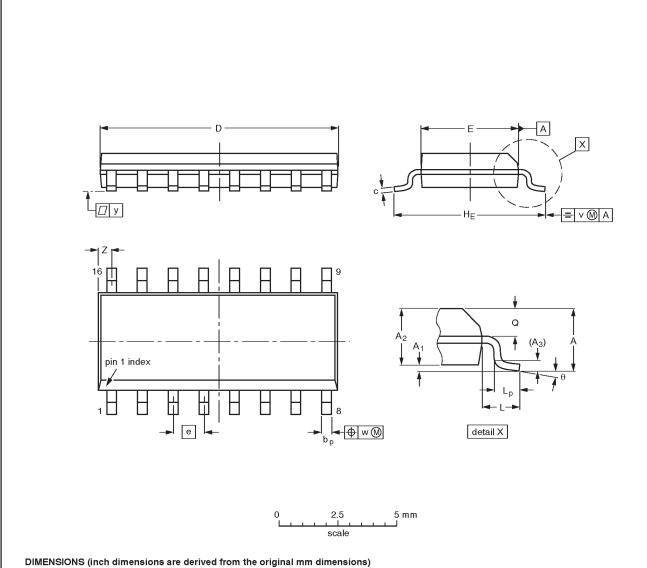
Product specification Philips Semiconductors

### 8-input multiplexer (3-State)

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### plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	Α1	A <sub>2</sub>	А3	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.0098 0.0039		0.01	0.019 0.014	0.0098 0.0075	0.39 0.38	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

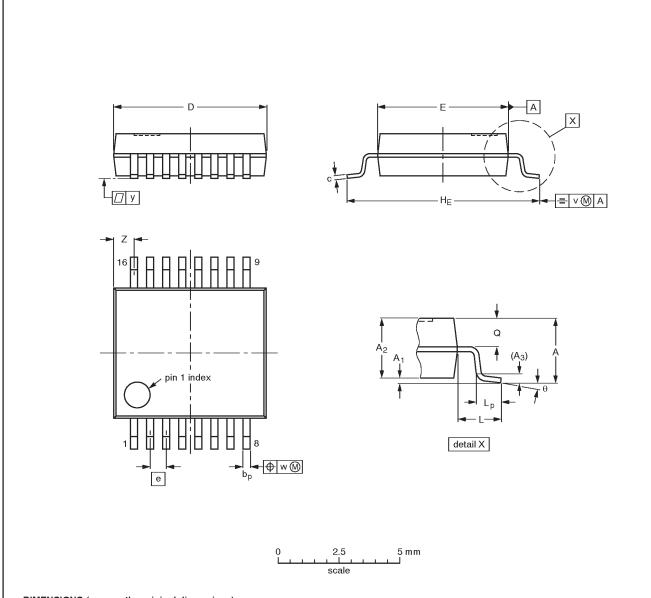
OUTLINE		REFER	EUROPEAN	ICCLIE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT109-1	076E07\$	MS-012AC				<del>91-08-13</del> 95-01-23	

# 8-input multiplexer (3-State)

74LV251

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	рb	c	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

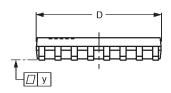
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE	
SOT338-1		MO-150AC				<del>94-01-14</del> 95-02-04	

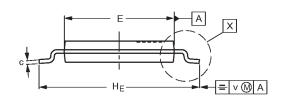
### 8-input multiplexer (3-State)

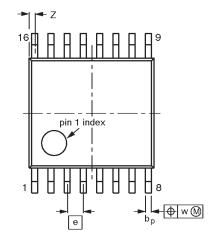
74LV251

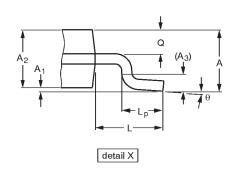
TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

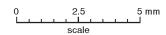
SOT403-1











#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bр	c	D <sup>(1)</sup>	E <sup>(2)</sup>	Φ	HE	L	Lp	Ø	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE				
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1990E DATE		
SOT403-1		MO-153				<del>-94-07-12-</del> 95-04-04		

### 8-input multiplexer (3-State)

74LV251

DEFINITIONS							
Data Sheet Identification	Product Status	Definition					
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.					
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